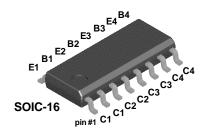


# **MMPQ2907**



# **PNP General Purpose Amplifier**

This device is designed for use as a general purpose amplifier and switch requiring collector currents to 500 mA. Sourced from Process 63.

## **Absolute Maximum Ratings\***

TA = 25°C unless otherwise noted

Symbol	Parameter	Value	Units
$V_{CEO}$	Collector-Emitter Voltage	40	V
V <sub>CBO</sub>	Collector-Base Voltage	60	V
V <sub>EBO</sub>	Emitter-Base Voltage	5.0	V
I <sub>C</sub>	Collector Current - Continuous		mA
T <sub>J</sub> , T <sub>stg</sub>	Operating and Storage Junction Temperature Range	-55 to +150	°C

<sup>\*</sup>These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

#### Thermal Characteristics TA = 25°C unless otherwise noted

Symbol	Characteristic	Max	Units
		MMPQ2907	
P <sub>D</sub>	Total Device Dissipation Derate above 25°C	1,000 8.0	mW mW/°C
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient Effective 4 Die Each Die	125 240	°C/W °C/W °C/W

<sup>\*</sup>Device mounted on FR-4 PCB 36 mm X 18 mm X 1.5 mm; mounting pad for the collector lead min. 6 cm<sup>2</sup>.

<sup>1)</sup> These ratings are based on a maximum junction temperature of 150 degrees C.

2) These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.

<sup>\*\*</sup>Device mounted on FR-4 PCB 1.6" X 1.6" X 0.06."

## **PNP General Purpose Amplifier**

(continued)

## **Electrical Characteristics**

TA = 25°C unless otherwise noted

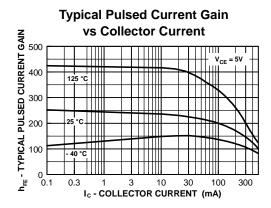
Symbol	Parameter	Test Conditions	Min	Max	Units
OEE CHAE	OFF CHARACTERISTICS				
			10	1	
$V_{(BR)CEO}$	Collector-Emitter Breakdown Voltage*	$I_C = 10 \text{ mA}, I_B = 0$	40		V
V <sub>(BR)CBO</sub>	Collector-Base Breakdown Voltage	$I_C = 10  \mu A, I_E = 0$	60		V
V <sub>(BR)EBO</sub>	Emitter-Base Breakdown Voltage	$I_E = 10  \mu A,  I_C = 0$	5.0		V
I <sub>EBO</sub>	Emitter Cutoff Current	V <sub>EB</sub> = 30 V		50	nA
I <sub>CBO</sub>	Collector Cutoff Current	V <sub>CB</sub> = 30 V		50	nA

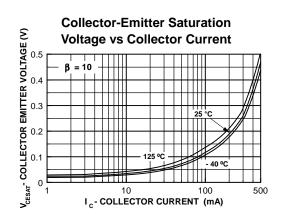
#### **ON CHARACTERISTICS**

h <sub>FE</sub>	DC Current Gain	I <sub>C</sub> = 10 mA, V <sub>CE</sub> = 10 V	75		
		$I_C = 150 \text{ mA}, V_{CE} = 10 \text{ V}^*$	100	300	
		$I_C = 300 \text{ mA}, V_{CE} = 10 \text{ V}$	30		
		$I_C = 500 \text{ mA}, V_{CE} = 10 \text{ V}^*$	50		
V <sub>CE(sat)</sub>	Collector-Emitter Saturation	$I_C = 150 \text{ mA}, I_B = 15 \text{ mA}$		0.4	V
	Voltage*	$I_C = 300 \text{ mA}, I_B = 30 \text{ mA}$		1.6	V
V <sub>BE(sat)</sub>	Base-Emitter Saturation Voltage	$I_C = 150 \text{ mA}, I_B = 15 \text{ mA}^*$		1.3	V
		$I_C = 300 \text{ mA}, I_B = 30 \text{ mA}$		2.6	V

<sup>\*</sup>Pulse Test: Pulse Width  $\leq$  300  $\mu$ s, Duty Cycle  $\leq$  2.0%

# **Typical Characteristics**





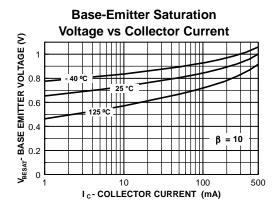
## **Spice Model**

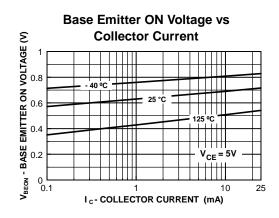
 $PNP \ (Is=650.6E-18 \ Xti=3 \ Eg=1.11 \ Vaf=115.7 \ Bf=231.7 \ Ne=1.829 \ Is=54.81f \ Ikf=1.079 \ Xtb=1.5 \ Br=3.563 \ Nc=2 \ Isc=0 \ Ikr=0 \ Rc=.715 \ Cjc=14.76p \ Mjc=.5383 \ Vjc=.75 \ Fc=.5 \ Cje=19.82p \ Mje=.3357 \ Vje=.75 \ Tr=111.3n \ Tf=603.7p \ Itf=.65 \ Vtf=5 \ Xtf=1.7 \ Rb=10)$ 

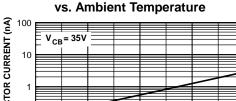
## **PNP General Purpose Amplifier**

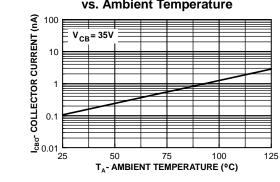
(continued)

### Typical Characteristics (continued)

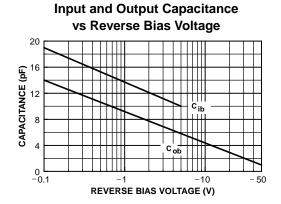


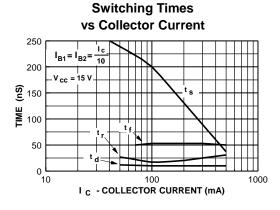


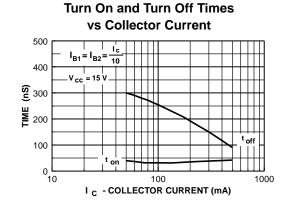




**Collector-Cutoff Current** 



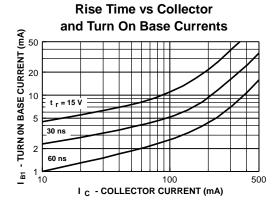


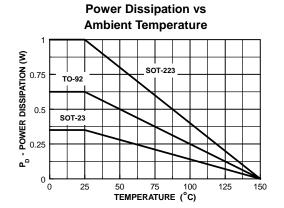


# **PNP General Purpose Amplifier**

(continued)

# **Typical Characteristics** (continued)





## **Test Circuits**

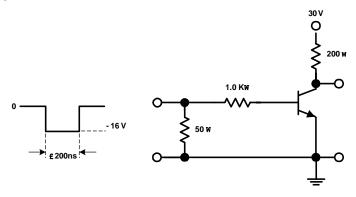


FIGURE 1: Saturated Turn-On Switching Time Test Circuit

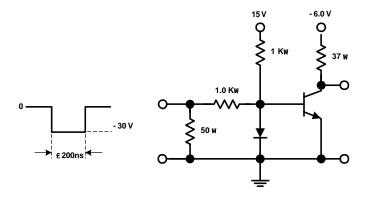


FIGURE 2: Saturated Turn-Off Switching Time Test Circuit

#### **TRADEMARKS**

The following are registered and unregistered trademarks Fairchild Semiconductor owns or is authorized to use and is not intended to be an exhaustive list of all such trademarks.

$ACEx^{TM}$	FAST ®	PACMAN™	SuperSOT™-3
Bottomless™	FASTr™	$POP^{TM}$	SuperSOT™-6
CoolFET™	GlobalOptoisolator™	PowerTrench ®	SuperSOT™-8
CROSSVOLT <sup>TM</sup>	GTO™	QFET™	SyncFET™
DenseTrench™	HiSeC™	QS™	TinyLogic™
DOME™	ISOPLANAR™	QT Optoelectronics™	UHC <sup>TM</sup>
EcoSPARK™	LittleFET™	Quiet Series™	UltraFET®
E <sup>2</sup> CMOS <sup>TM</sup>	MicroFET™	SILENT SWITCHER ®	$VCX^{TM}$
EnSigna™	MICROWIRE™	SMART START™	

FACT Quiet Series<sup>TM</sup> OPTOPLANAR<sup>TM</sup> Star\* Power<sup>TM</sup>
FACT Quiet Series<sup>TM</sup> OPTOPLANAR<sup>TM</sup> Stealth<sup>TM</sup>

#### **DISCLAIMER**

FAIRCHILD SEMICONDUCTOR RESERVES THE RIGHT TO MAKE CHANGES WITHOUT FURTHER NOTICE TO ANY PRODUCTS HEREIN TO IMPROVE RELIABILITY, FUNCTION OR DESIGN. FAIRCHILD DOES NOT ASSUME ANY LIABILITY ARISING OUT OF THE APPLICATION OR USE OF ANY PRODUCT OR CIRCUIT DESCRIBED HEREIN; NEITHER DOES IT CONVEY ANY LICENSE UNDER ITS PATENT RIGHTS, NOR THE RIGHTS OF OTHERS.

#### LIFE SUPPORT POLICY

FAIRCHILD'S PRODUCTS ARE NOT AUTHORIZED FOR USE AS CRITICAL COMPONENTS IN LIFE SUPPORT DEVICES OR SYSTEMS WITHOUT THE EXPRESS WRITTEN APPROVAL OF FAIRCHILD SEMICONDUCTOR CORPORATION. As used herein:

- 1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, or (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in significant injury to the user.
- 2. A critical component is any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

#### **PRODUCT STATUS DEFINITIONS**

#### **Definition of Terms**

Datasheet Identification	Product Status	Definition
Advance Information	Formative or In Design	This datasheet contains the design specifications for product development. Specifications may change in any manner without notice.
Preliminary	First Production	This datasheet contains preliminary data, and supplementary data will be published at a later date. Fairchild Semiconductor reserves the right to make changes at any time without notice in order to improve design.
No Identification Needed	Full Production	This datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice in order to improve design.
Obsolete	Not In Production	This datasheet contains specifications on a product that has been discontinued by Fairchild semiconductor. The datasheet is printed for reference information only.

# **X-ON Electronics**

Largest Supplier of Electrical and Electronic Components

Click to view similar products for Bipolar Transistors - BJT category:

Click to view products by ON Semiconductor manufacturer:

Other Similar products are found below:

619691C MCH4017-TL-H MJ15024/WS MJ15025/WS BC546/116 BC556/FSC BC557/116 BSW67A HN7G01FU-A(T5L,F,T NJVMJD148T4G NSVMMBT6520LT1G NTE187A NTE195A NTE2302 NTE2302 NTE2330 NTE2353 NTE316 IMX9T110 NTE63 NTE65 C4460 SBC846BLT3G 2SA1419T-TD-H 2SA1721-O(TE85L,F) 2SA1727TLP 2SA2126-E 2SB1202T-TL-E 2SB1204S-TL-E 2SC5488A-TL-H 2SD2150T100R SP000011176 FMC5AT148 2N2369ADCSM 2SB1202S-TL-E 2SC2412KT146S 2SC4618TLN 2SC5490A-TL-H 2SD1816S-TL-E 2SD1816T-TL-E CMXT2207 TR CPH6501-TL-E MCH4021-TL-E BC557B TTC012(Q) BULD128DT4 JANTX2N3810 Jantx2N5416 US6T6TR KSF350 068071B